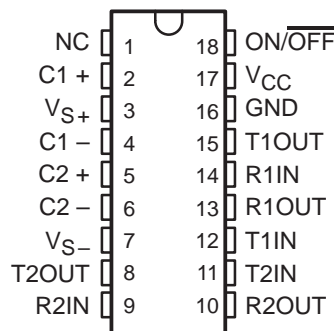


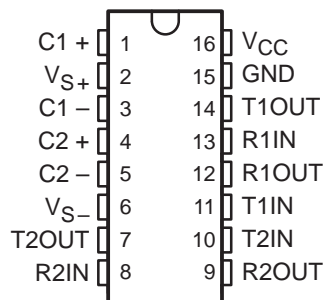
- Operates With Single 5-V Power Supply
- Generates  $\pm 9$ -V Supply Voltages With Only 1- $\mu$ F Capacitors
- Designed to Avoid Latch-Up
- CMOS Comparable Low Power . . . 60 mW
- Features Superior to CMOS:
  - Improved Speed . . . Operates Over 64K Baud
  - Improved Protection . . . Outputs Can Be Forced to  $\pm 30$  V Without Damage
  - 3-State Outputs Are at High Impedance When Off
- Power Additional EIA-232 Drivers . . . 10 mA
- 1- $\mu$ A Supply Current in Shutdown
- Available With or Without Shutdown
- Suitable for ANSI/EIA-232-D-1986 Applications (Revision of EIA Std RS-232-C)
- Designed to Be Interchangeable With Linear Technology LT1080 and LT1081

**LT1080C, LT1080I . . . DW OR N PACKAGE**  
**(TOP VIEW)**



NC – No internal connection

**LT1081C, LT1081I . . . DW OR N PACKAGE**  
**(TOP VIEW)**



## description

The LT1080 and LT1081 are dual driver/receivers that include a charge pump to supply EIA-232 voltage levels from a single 5-V supply. These interface-optimized devices are designed to avoid latch-up and provide a realistic balance between CMOS levels of power dissipation and real-world requirements for ruggedness. The driver outputs are fully protected against overload and can be shorted to  $\pm 30$  V. Unlike CMOS devices, the advanced architecture of the LT1080 and LT1081 does not load the signal line when shut down or when the power is off. Both the receiver and EIA-232 outputs are put into a high-impedance state. An advanced output stage allows driving higher capacitive loads at higher speeds with exceptional resistance to ESD.

Applications for these devices include portable computers, battery-powered EIA-232 systems, power-supply generators, terminals, and modems.

The LT1080C and LT1081C are characterized for operation from 0°C to 70°C. The LT1080I and LT1081I are characterized for operation from –40°C to 85°C.

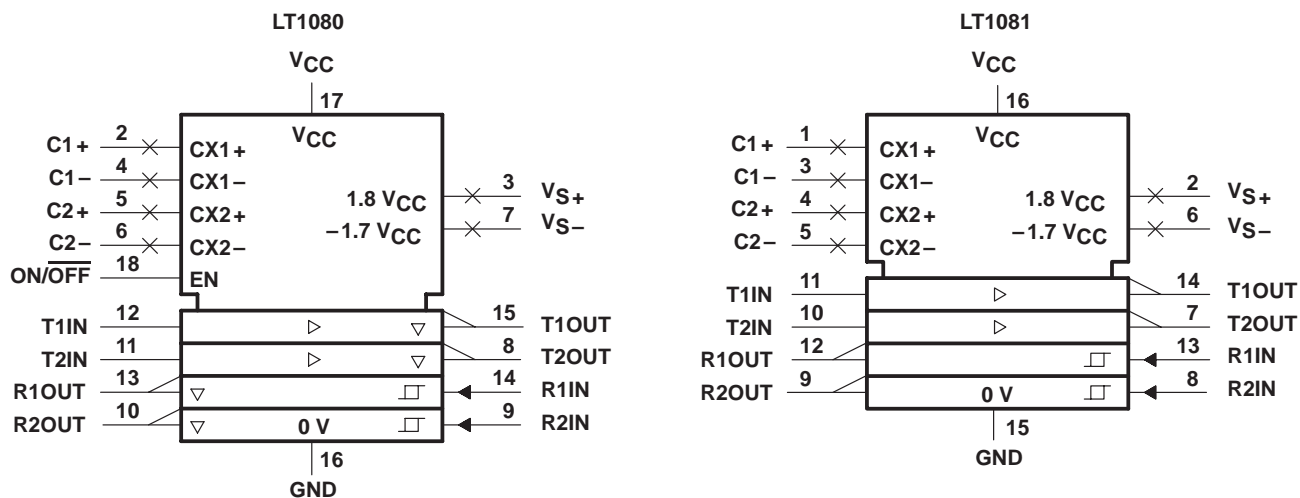
# LT1080, LT1081

## ADVANCED LOW-POWER

### 5-V DUAL EIA-232 DRIVER/RECEIVERS

SLLS050A – D3121, SEPTEMBER 1989 – REVISED FEBRUARY 1991

#### logic symbols†



† These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

#### Terminal Functions

PIN NAME	NO.†	I/O	DESCRIPTION
C1 +	2 [1]		External capacitor C1
C1 –	4 [3]		
C2 +	5 [4]		External capacitor C2
C2 –	6 [5]		
GND	16 [15]		Ground pin
ON/OFF	18	I	Controls the operation mode and is TTL/CMOS compatible. A low logic level places the device in the shutdown mode, which reduces input supply current to near zero and places both driver and receiver outputs in a high-impedance state. This input is not available on the LT1081.
R1IN	14 [13]	I	Receiver input. Accepts EIA-232 voltage levels ( $\pm 30$ V) and has hysteresis to provide noise immunity.
R2IN	9 [8]	I	Same as R1IN
R1OUT	13 [12]	O	Receiver output with TTL/CMOS voltage levels. Output is in a high-impedance state when in the shutdown mode or when $V_{CC} = 0$ to allow bus operation. Fully short-circuit protected to GND or $V_{CC}$ with power on, power off, or in the shutdown mode.
R2OUT	10 [9]	O	Same as R1OUT
T1IN	12 [11]	I	EIA-232 driver input pin. Input is TTL/CMOS compatible. Unused inputs should be tied to $V_{CC}$ .
T2IN	11 [10]	I	Same as T1IN
T1OUT	15 [14]	O	Driver output with EIA-232 voltage levels. Outputs are in a high-impedance state when in the shutdown mode or when $V_{CC} = 0$ to allow bus operation. Fully short-circuit protected to GND or $V_{CC}$ with power on, power off, or in the shutdown mode.
T2OUT	8 [7]	O	Same as T1OUT
VS+	3 [2]		Positive supply for EIA-232 drivers. Requires an external capacitor (1- $\mu$ F) for charge storage.
VS–	7 [6]		Negative supply for EIA-232 drivers. Requires an external capacitor (1- $\mu$ F) for charge storage.
VCC	17 [16]		Input supply pin. Supply current drops to near zero in the shutdown mode. Driver and receiver outputs are in a high-impedance state when $V_{CC} = 0$ .

† Pin numbers in brackets are for the LT1081.

**absolute maximum ratings over operating free-air temperature range (unless otherwise noted)**

Supply voltage, $V_{CC}$ (see Note 1)	6 V
Positive output supply voltage	12 V
Negative output supply voltage	–12 V
Input voltage range: Driver	$\pm 12$ V
Receiver	$\pm 30$ V
ON/OFF	GND to 12 V
Output voltage range: T1OUT, T2OUT	$V_{S-} + 30$ V to $V_{S+} - 30$ V
R1OUT, R2OUT	–0.3 V to $V_{CC} + 0.3$ V
Duration of output short circuit at (or below) 25°C: $V_{S+}$	30 s
$V_{S-}$	30 s
Driver or receiver output	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range: LT1080C, LT1081C	0°C to 70°C
LT1080I, LT1081I	–40°C to 85°C
Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

NOTE 1: All voltage values are with respect to network ground terminal.

**DISSIPATION RATING TABLE**

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING
DW	1025 mW	8.2 mW/°C	656 mW	533 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW

**recommended operating conditions**

	LT1080C, LT1081C			LT1080I, LT1081I			UNIT
	MIN	TYP	MAX	MIN	TYP	MAX	
Supply voltage, $V_{CC}$	4.5	5	5.5	4.5	5	5.5	V
High-level input voltage, $V_{IH}$ (T1IN, T2IN)	2		5.5	2		5.5	V
Low-level input voltage, $V_{IL}$ (T1IN, T2IN)			0.8			0.8	V
Operating free-air temperature, $T_A$	0		70	–40		85	°C

**LT1080, LT1081**  
**ADVANCED LOW-POWER**  
**5-V DUAL EIA-232 DRIVER/RECEIVERS**  
 SLLS050A – D3121, SEPTEMBER 1989 – REVISED FEBRUARY 1991

**electrical characteristics over recommended ranges of supply voltage and operating free-air temperature,  $V_I = 3\text{ V}$  (unless otherwise noted)**

**driver section**

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{OM+}$ Positive-peak output voltage	$R_L = 3\text{ k}\Omega$ to GND	5	7.5		V
$V_{OM-}$ Negative-peak output voltage	$R_L = 3\text{ k}\Omega$ to GND	-5	-6.5		V
$I_{IH}$ High-level input current	$V_I = 2\text{ V}$ to $5.5\text{ V}$		5	20	$\mu\text{A}$
$I_{IL}$ Low-level input current	$V_I \leq 0.8\text{ V}$		-5	-20	$\mu\text{A}$
$I_{OHS}$ Output short-circuit current (sourcing)	$V_I = 0$ , $V_O = 0$ , $T_A = 25^\circ\text{C}$	-7	12		mA
$I_{OLS}$ Output short-circuit current (sinking)	$V_I = 2\text{ V}$ , $V_O = 0$ , $T_A = 25^\circ\text{C}$	7	-12		mA
$I_{OZ}$ High-impedance output current	Shutdown mode, $V_O = \pm 30\text{ V}$			100	$\mu\text{A}$

**receiver section**

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{T+}$ Positive-going input threshold voltage	LT1080C, LT1081C		1.7	2.4	V
	LT1080I, LT1081I		1.7	3	
$V_{T-}$ Negative-going input threshold voltage	LT1080C, LT1081C	0.8	1.3		V
	LT1080I, LT1081I	0.2	1.3		
$V_{hys}$ Input hysteresis		0.1	0.4	1	V
$r_i$ Input resistance	$T_A = 25^\circ\text{C}$	3	5	7	$\text{k}\Omega$
$V_{OH}$ High-level output voltage	$I_{OH} = -160\text{ }\mu\text{A}$ , $V_{CC} = 5\text{ V}$	3.5	4.8		V
$V_{OL}$ Low-level output voltage	$I_{OL} = 1.6\text{ mA}$		0.2	0.4	V
$I_{OSH}$ Output short-circuit current (sourcing)	$V_I = 3\text{ V}$ , $V_O = 0$ , $T_A = 25^\circ\text{C}$	-0.6	-1		mA
$I_{OSL}$ Output short-circuit current (sinking)	$V_I = 3\text{ V}$ , $V_O = V_{CC}$ , $T_A = 25^\circ\text{C}$	10	20		mA
$I_{OZ}$ High-impedance output current	Shutdown mode, $V_O = 0$ to $V_{CC}$			10	$\mu\text{A}$

**power supply section,  $V_{CC} = 5\text{ V}$ , driver outputs low (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
$V_{S+}$ Supply output voltage	$I_S = 0$ , $T_A = 25^\circ\text{C}$	8	9		V
	$I_S = 10\text{ mA}$ , $T_A = 25^\circ\text{C}$	7	8		
	$I_S = 15\text{ mA}$ , $T_A = 25^\circ\text{C}$	6.5	7.5		
$V_{S-}$ Supply output voltage	$I_S = 0$ , $T_A = 25^\circ\text{C}$	-7.5	-8.5		V
	$I_S = 10\text{ mA}$ , $T_A = 25^\circ\text{C}$	-5.5	-6.5		
	$I_S = 15\text{ mA}$ , $T_A = 25^\circ\text{C}$	-5	-6		
$I_{CC}$ Supply current			10	22	mA
$I_{CC(off)}$ Off-state supply current (LT1080)	ON/OFF at $0.4\text{ V}$			100	$\mu\text{A}$
$I_I$ Input current (ON/OFF) (LT1080)	$V_I = 5\text{ V}$			80	$\mu\text{A}$
	$V_I = 0\text{ V}$			-15	

† All typical values are at  $V_{CC} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

**operating characteristics over recommended range of supply voltage,  $V_I = 3\text{ V}$ ,  $T_A = 25^\circ\text{C}$**

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR Driver slew rate	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ , $C_L = 560\text{ pF}$ , See Note 2	4	15	30	V/ $\mu\text{s}$
$t_r(\text{supply})$ Supply rise time (see Note 3)	$C1 - C4 = 1\text{ }\mu\text{F}$		1		ms

NOTES: 2. Meets EIA-232-D specifications for capacitive loads greater than  $560\text{ pF}$ .

3. Time from either shutdown input ON/OFF (LT1080) goes active high or  $V_{CC}$  power on (LT1081) until the output voltages reach  $V_{S+} \geq 6\text{ V}$  and  $V_{S-} \leq -6\text{ V}$ .



# TYPICAL CHARACTERISTICS†

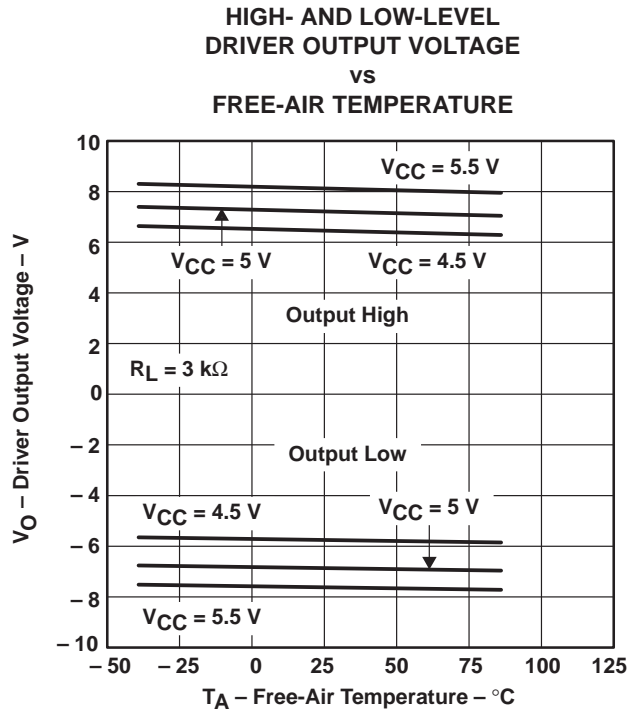


Figure 1

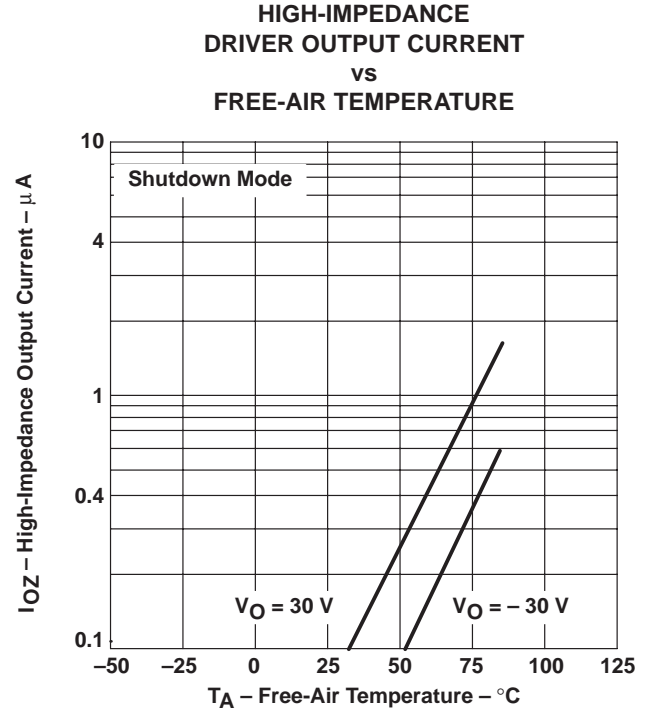


Figure 2

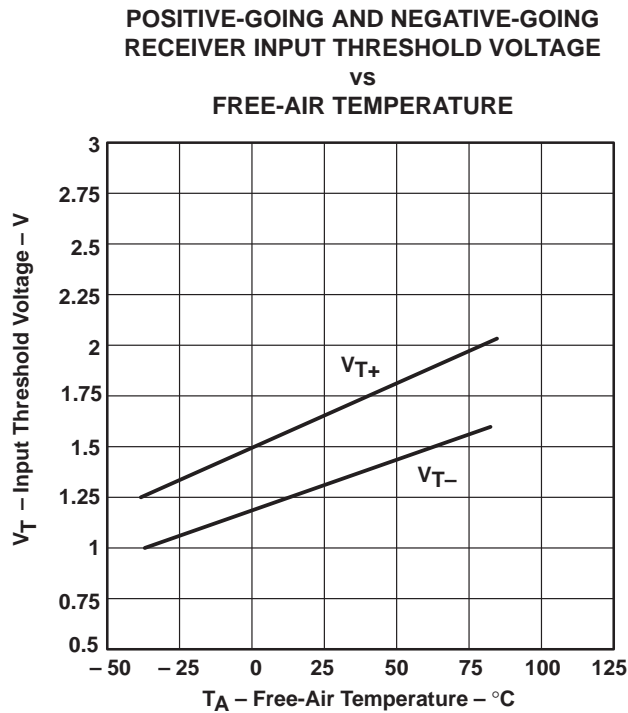


Figure 3

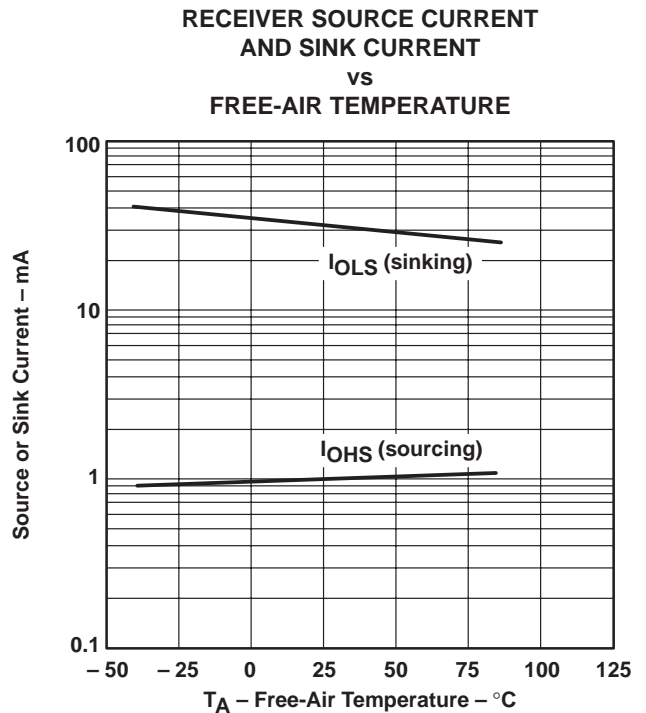


Figure 4

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

# TYPICAL CHARACTERISTICS†

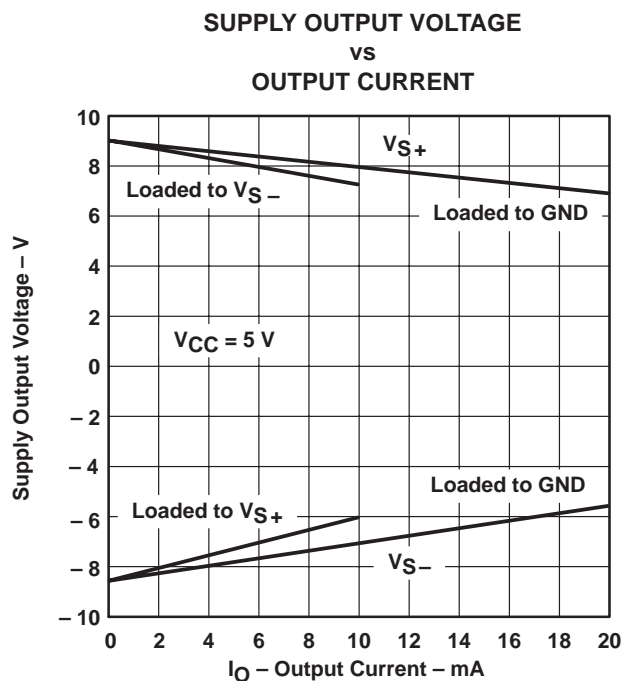


Figure 5

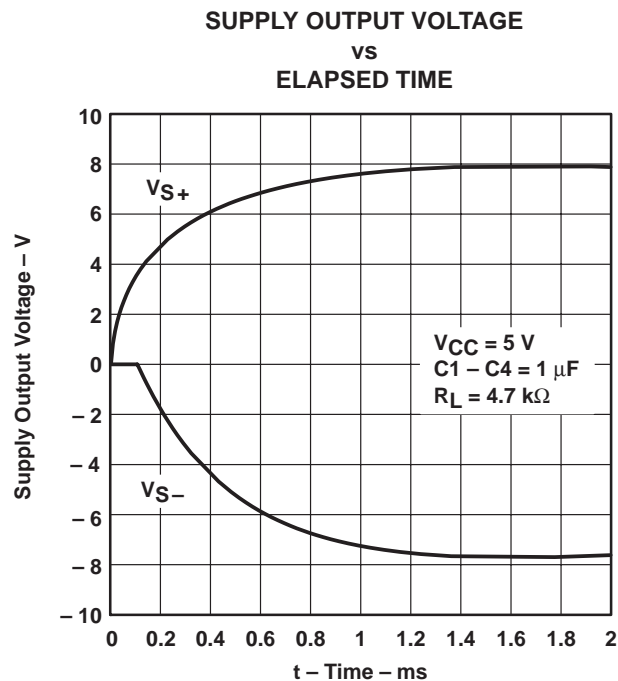


Figure 6

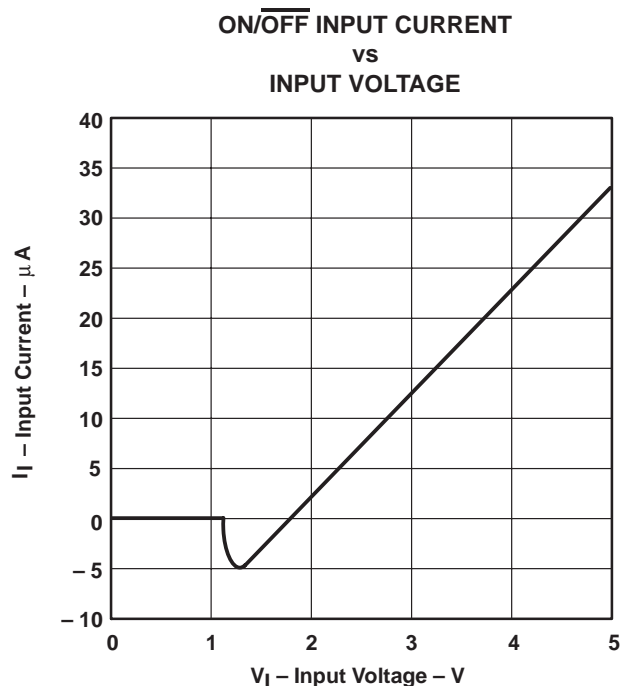


Figure 7

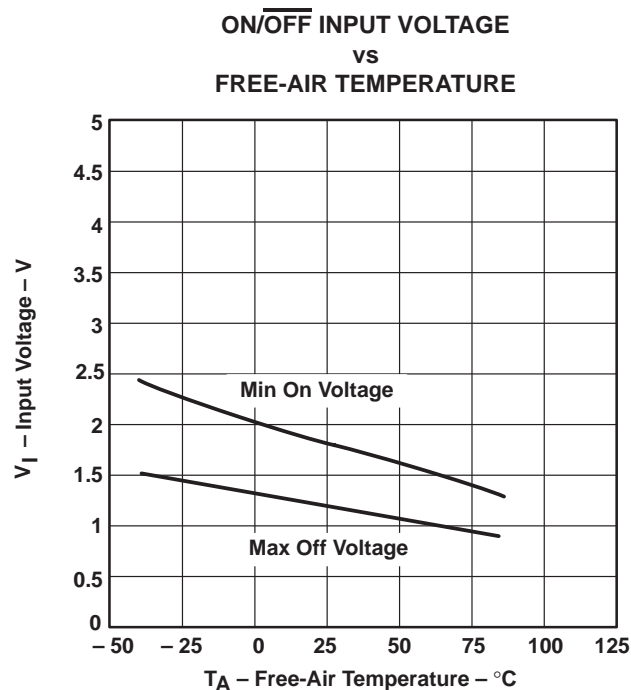


Figure 8

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

# TYPICAL CHARACTERISTICS†

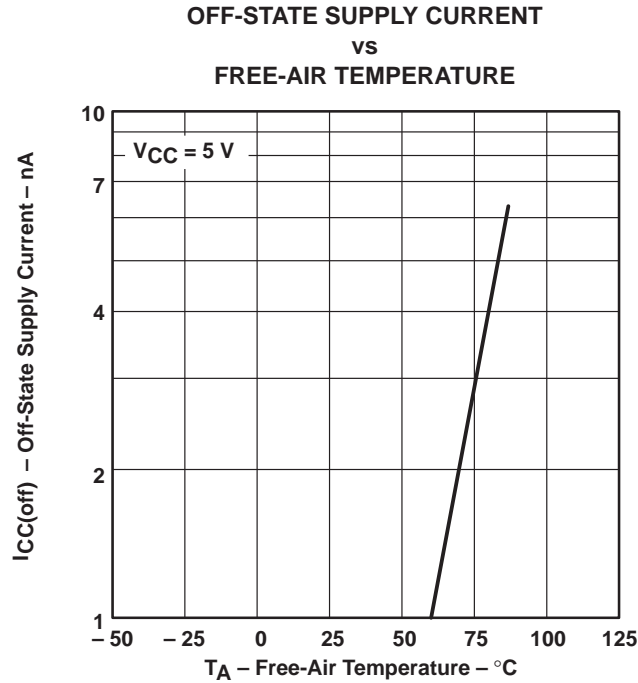


Figure 9

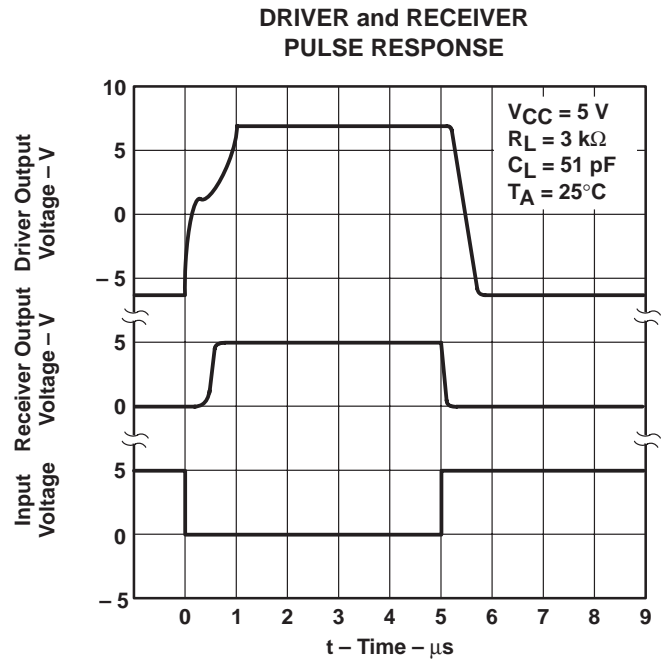


Figure 10

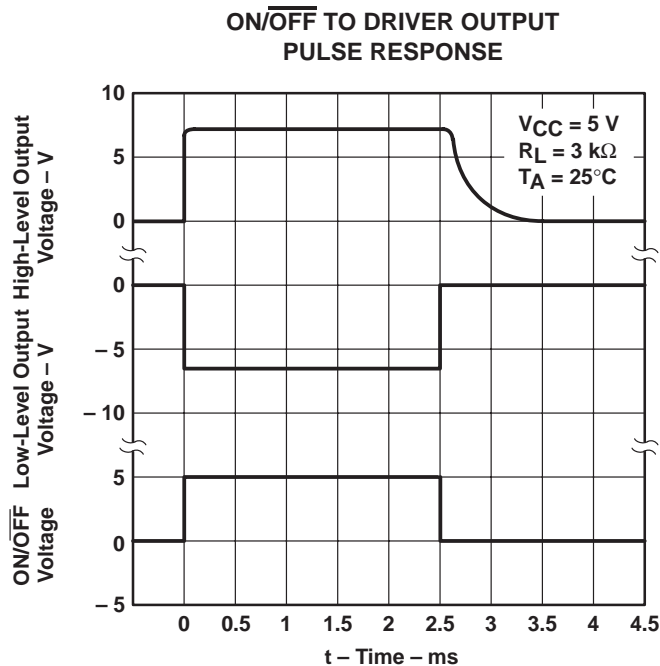


Figure 11

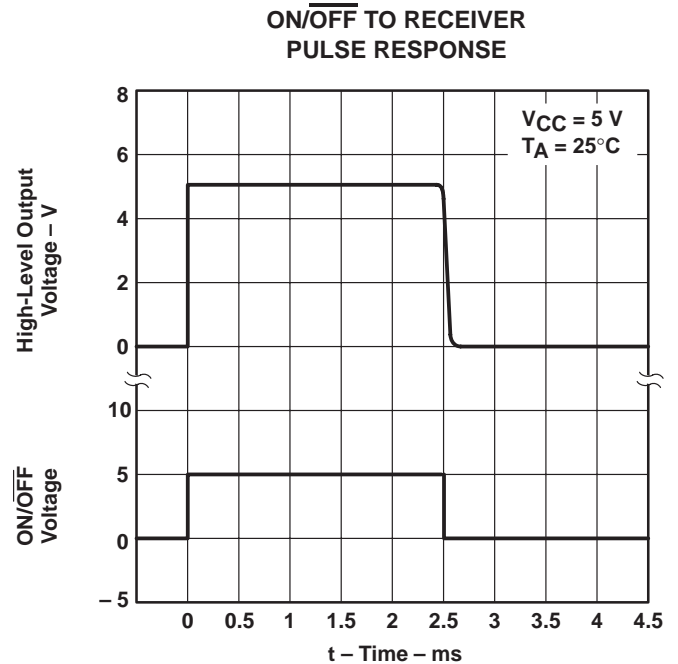


Figure 12

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

## APPLICATION INFORMATION

The driver output stage of the LT1080 offers significantly improved protection over older bipolar and CMOS designs (see Figures 13 and 14). In addition to limiting current, the driver output can be externally forced to  $\pm 30$  V without damage, excessive current flow, or supply disruption. Some drivers have diodes connected between the outputs and the supplies, allowing externally applied voltages to cause excessive supply voltage to develop.

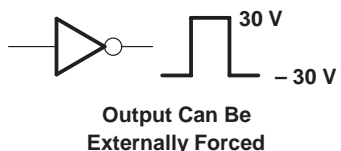


Figure 13. LT1080/LT1081 Driver

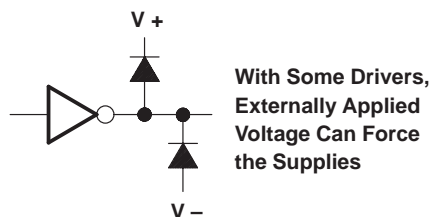


Figure 14. Older EIA-232 Drivers and CMOS Drivers

Placing the LT1080 in the shutdown mode (pin 18 low) puts both the driver and receiver outputs in a high-impedance state. This allows for bus operation and transceiver applications (see Figures 15–17). The shutdown mode also drops input supply current ( $V_{CC}$ ) to near zero for power-conscious systems.

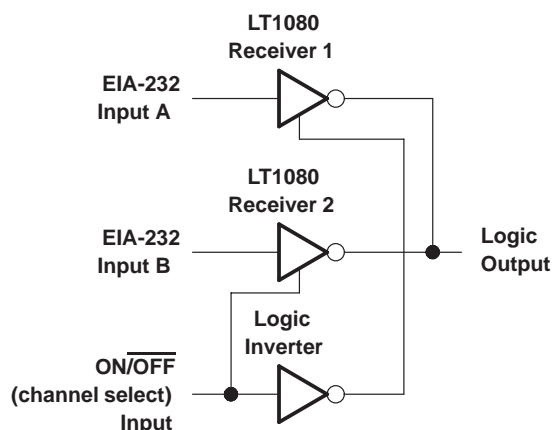


Figure 15. Sharing a Receiver Line

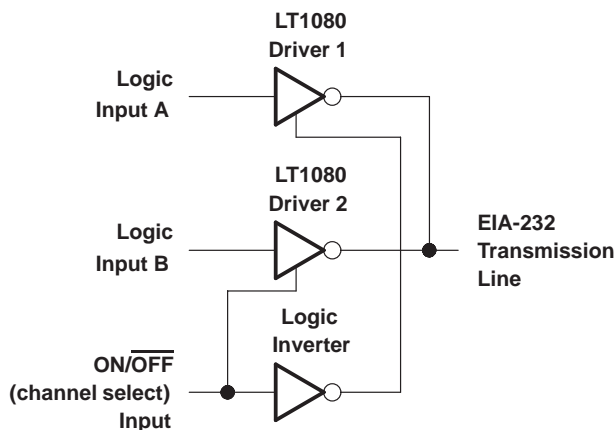
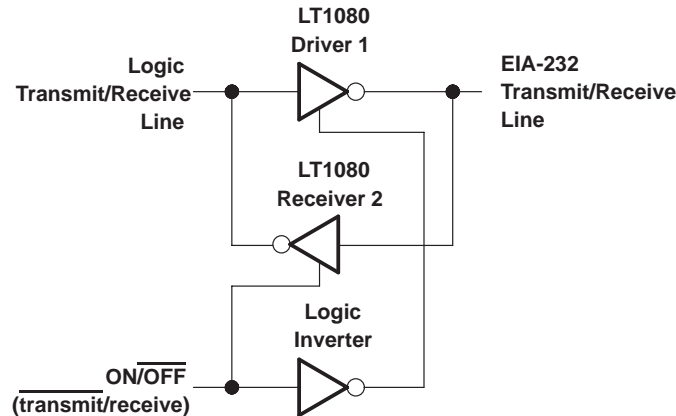


Figure 16. Sharing a Transmitter Line



## APPLICATION INFORMATION

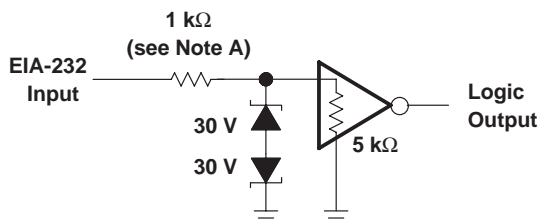


**Figure 17. Transceiver**

To protect against receiver input overloads in excess of  $\pm 30$  V, a voltage clamp can be placed on the data line and still maintain EIA-232 compatibility (see Figure 18).

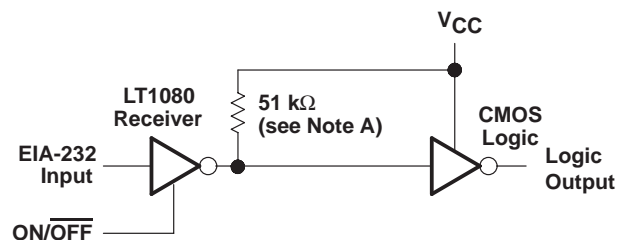
When driving CMOS logic from a receiver that will be used in the shutdown mode and when there is no other active receiver on the line, a 51-k $\Omega$  resistor can be placed from the logic input to  $V_{CC}$  to force a definite logic level when the receiver output is in a high-impedance state (see Figure 19).

The generated driver supplies ( $V_{S+}$  and  $V_{S-}$ ) may be used to power external circuitry such as other EIA-232 drivers or operational amplifiers (see Figure 20). They should be loaded with care, since excessive loading can cause the generated supply voltages to drop, causing the EIA-232 driver output voltages to fall below EIA-232 requirements. See Figure 5 for a comparison of generated supply voltage versus supply current.



NOTE A: A PTC thermistor will allow continuous overload of greater than  $\pm 100$  V.

**Figure 18. Input Overload Protection**



NOTE A: Forces logic input state when  $V_I$  is low.

**Figure 19. Forcing a Definite Logic Level**



## APPLICATION INFORMATION



### Figure 22. Operating With 5 V and 12 V



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